

Si No	Device	V _{CEO} Volts min	V _{CB0} Volts min	V _{EB0} Volts min	h _{FE} at bias min /max	I _C mA	V _{CE} Volts	I _{CM} mA max	P _{tot} mW max	I _{CBO} μA typ	V _{CE} (Sat) Volts typ	f _r MHz typ	C _{ob} pF typ	t _s ns typ	N _F dB typ	Package
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NPN GENERAL PURPOSE/SWITCHING TRANSISTORS

56.	BCY 56	45	45	5	100/450	2	5	100	300	.1	.2	85	—	—	1.5	TO 18
57.	BCY 57	20	25	5	200/800	2	5	100	300	.1	.2	100	—	—	1.5	"
58.	BCY58VII	32	32	7	125/250	2	5	200	330	.1	.2	280	—	—	2	"
59.	BCY58VIII				175/350											"
60.	BCY 58 IX				250/500											"
61.	BCY 58X				350/700											"
62.	BCY 59VII	45	45	7	125/250	2	5	200	330	.1	.2	280	—	—	2	"
63.	BCY 59VIII				175/350											"
64.	BCY 59IX				250/500											"
65.	BCY 59X				350/500											"

PNP GENERAL PURPOSE/SWITCHING TRANSISTORS

66.	BCY 70	40	50	5	100/290	1	10	200	350	.05	.5	250	—	—	2	TO 18
67.	BCY 71	45	45	5	100/400	1	10	200	350	.05	.5	250	—	—	2	"
68.	BCY 72	25	30	5	100min.	1	10	200	350	.05	.5	250	—	—	2	"
69.	BCY 78VII	32	32	5	125/250	2	5	200	345	.1	.2	180	—	—	2	"
70.	BCY 78VIII				175/350										"	"
71.	BCY 78IX			5	250/500										"	"
72.	BCY 78X				350/700										"	"
73.	BCY 79VII	45	45		125/250	2	5	200	345	.1	.2	180	—	—	2	TO 18
74.	BCY 79VIII				175/350										"	"
75.	BCY 79IX				250/500										"	"
76.	BCY 79X				350/700										"	"

FIELD EFFECT TRANSISTORS (N-CHANNEL)

Si No	Device	B _V GSS Volts min	I _{GSS} nA max	V _P Volts max	g _m μmhos	N _f dB typ	P _{tot} mW max	I _{oss} mA	Package
77.	BFW 10	30	0.5	8	3500/6500	2.5	300	8-20	T072
78.	BFW 11	30	0.5	6	3500/6500	2.5	300	4-10	"
79.	BFW 61	25	0.5	8	3500/6500	2.5	300	2-20	"

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